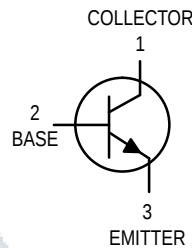


Amplifier Transistors

NPN Silicon

BC546, B
BC547, A, B, C
BC548, A, B, C



MAXIMUM RATINGS

Rating	Symbol	BC 546	BC 547	BC 548	Unit
Collector–Emitter Voltage	V_{CEO}	65	45	30	Vdc
Collector–Base Voltage	V_{CBO}	80	50	30	Vdc
Emitter–Base Voltage	V_{EBO}	6.0			Vdc
Collector Current — Continuous	I_C	100			mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0			mW mW/°C
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12			Watt mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150			°C

THERMAL CHARACTERISTICS

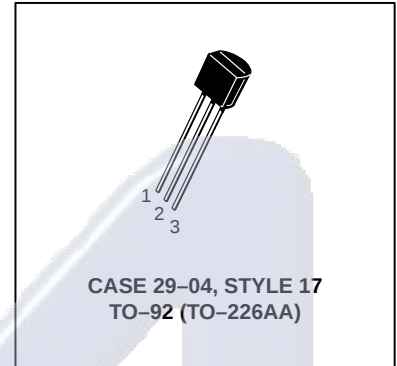
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ($I_C = 1.0\text{ mA}$, $I_B = 0$)	BC546 BC547 BC548	$V_{(BR)CEO}$	65 45 30	— — —	— — —	V
Collector–Base Breakdown Voltage ($I_C = 100\text{ }\mu\text{Adc}$)	BC546 BC547 BC548	$V_{(BR)CBO}$	80 50 30	— — —	— — —	V
Emitter–Base Breakdown Voltage ($I_E = 10\text{ }\mu\text{A}$, $I_C = 0$)	BC546 BC547 BC548	$V_{(BR)EBO}$	6.0 6.0 6.0	— — —	— — —	V
Collector Cutoff Current ($V_{CE} = 70\text{ V}$, $V_{BE} = 0$) ($V_{CE} = 50\text{ V}$, $V_{BE} = 0$) ($V_{CE} = 35\text{ V}$, $V_{BE} = 0$) ($V_{CE} = 30\text{ V}$, $T_A = 125^\circ\text{C}$)	BC546 BC547 BC548 BC546/547/548	I_{CES}	— — — —	0.2 0.2 0.2 —	15 15 15 4.0	nA μA



BC546, B BC547, A, B, C BC548, A, B, C**ELECTRICAL CHARACTERISTICS** ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS						
DC Current Gain ($I_C = 10\ \mu\text{A}$, $V_{CE} = 5.0\ \text{V}$)	BC547A/548A BC546B/547B/548B BC548C	h_{FE}	— — —	90 150 270	— — —	—
($I_C = 2.0\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$)	BC546 BC547 BC548 BC547A/548A BC546B/547B/548B BC547C/BC548C		110 110 110 110 200 420	— — — 180 290 520	450 800 800 220 450 800	
($I_C = 100\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$)	BC547A/548A BC546B/547B/548B BC548C		— — —	120 180 300	— — —	
Collector–Emitter Saturation Voltage ($I_C = 10\ \text{mA}$, $I_B = 0.5\ \text{mA}$) ($I_C = 100\ \text{mA}$, $I_B = 5.0\ \text{mA}$) ($I_C = 10\ \text{mA}$, $I_B = \text{See Note 1}$)		$V_{CE(\text{sat})}$	— — —	0.09 0.2 0.3	0.25 0.6 0.6	V
Base–Emitter Saturation Voltage ($I_C = 10\ \text{mA}$, $I_B = 0.5\ \text{mA}$)		$V_{BE(\text{sat})}$	—	0.7	—	V
Base–Emitter On Voltage ($I_C = 2.0\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$) ($I_C = 10\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$)		$V_{BE(\text{on})}$	0.55 —	— —	0.7 0.77	V
SMALL–SIGNAL CHARACTERISTICS						
Current–Gain — Bandwidth Product ($I_C = 10\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$, $f = 100\ \text{MHz}$)	BC546 BC547 BC548	f_T	150 150 150	300 300 300	— — —	MHz
Output Capacitance ($V_{CB} = 10\ \text{V}$, $I_C = 0$, $f = 1.0\ \text{MHz}$)		C_{obo}	—	1.7	4.5	pF
Input Capacitance ($V_{EB} = 0.5\ \text{V}$, $I_C = 0$, $f = 1.0\ \text{MHz}$)		C_{ibo}	—	10	—	pF
Small–Signal Current Gain ($I_C = 2.0\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$, $f = 1.0\ \text{kHz}$)	BC546 BC547/548 BC547A/548A BC546B/547B/548B BC547C/548C	h_{fe}	125 125 125 240 450	— — 220 330 600	500 900 260 500 900	—
Noise Figure ($I_C = 0.2\ \text{mA}$, $V_{CE} = 5.0\ \text{V}$, $R_S = 2\ \text{k}\Omega$, $f = 1.0\ \text{kHz}$, $\Delta f = 200\ \text{Hz}$)	BC546 BC547 BC548	NF	— — —	2.0 2.0 2.0	10 10 10	dB

Note 1: I_B is value for which $I_C = 11\ \text{mA}$ at $V_{CE} = 1.0\ \text{V}$.

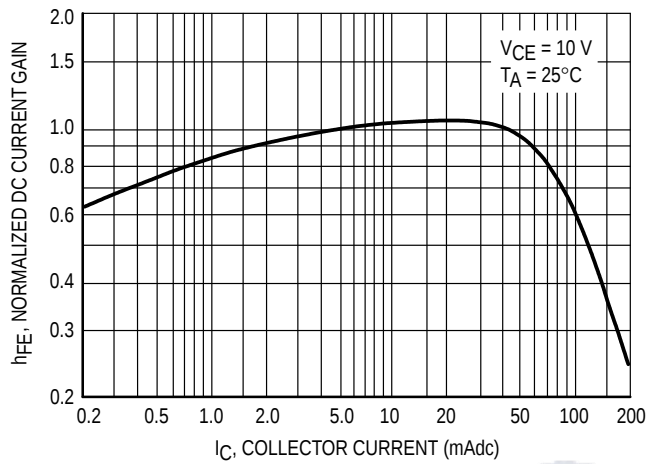


Figure 1. Normalized DC Current Gain

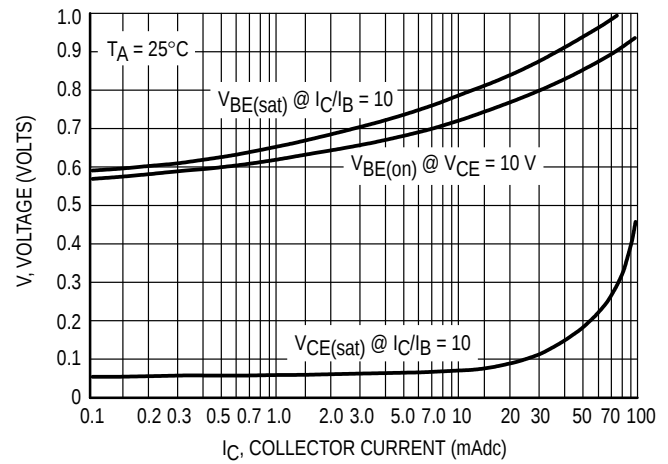


Figure 2. "Saturation" and "On" Voltages

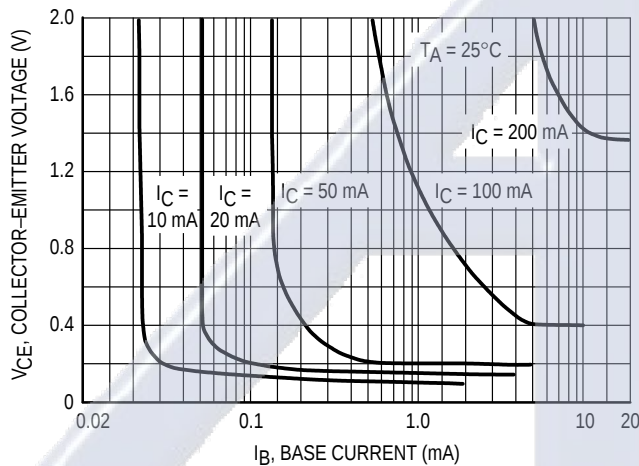


Figure 3. Collector Saturation Region

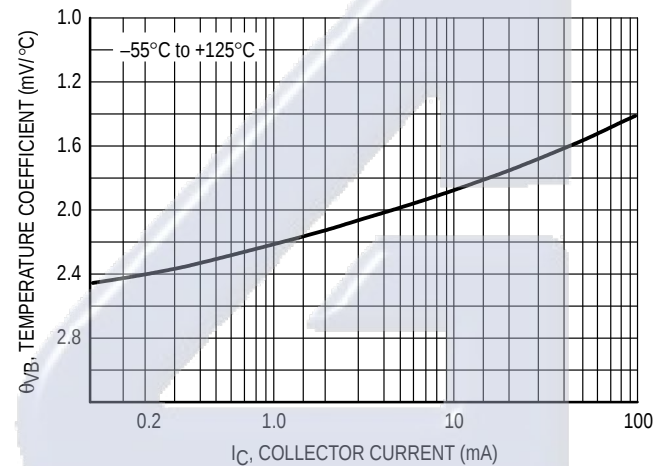


Figure 4. Base-Emitter Temperature Coefficient

BC547/BC548

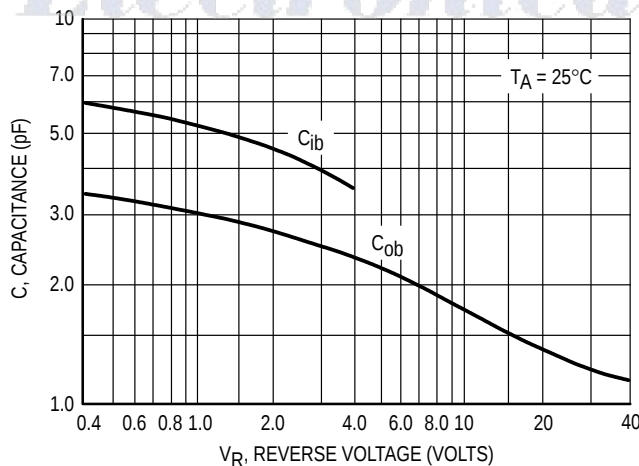


Figure 5. Capacitances

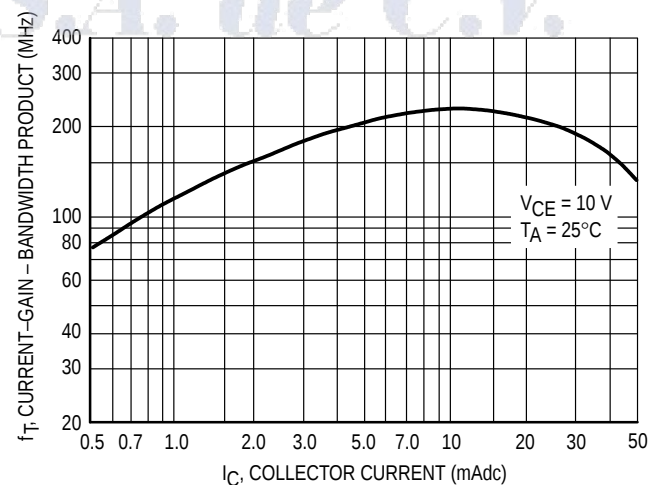


Figure 6. Current-Gain - Bandwidth Product

BC547/BC548

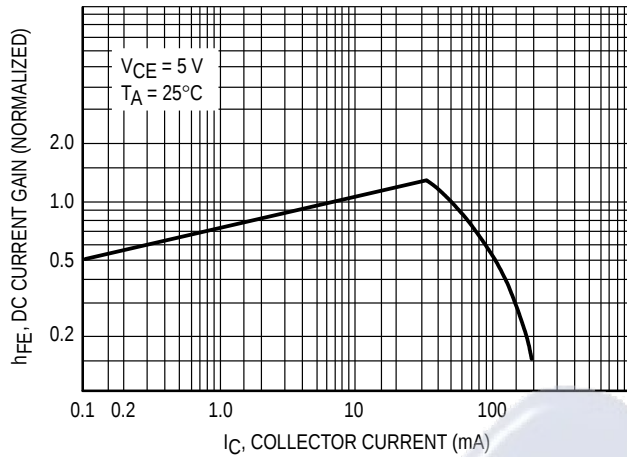


Figure 7. DC Current Gain

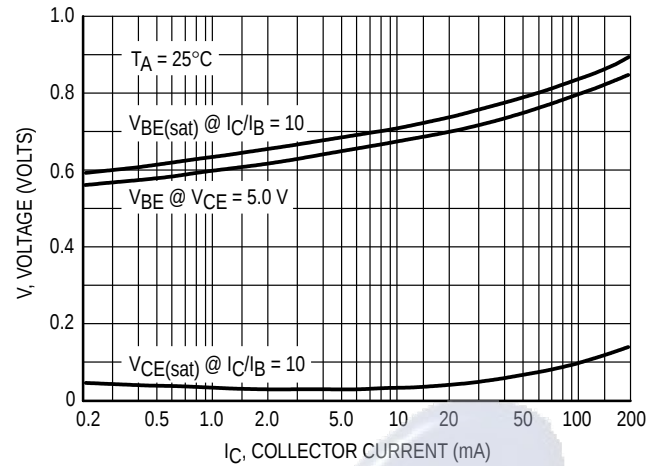


Figure 8. "On" Voltage

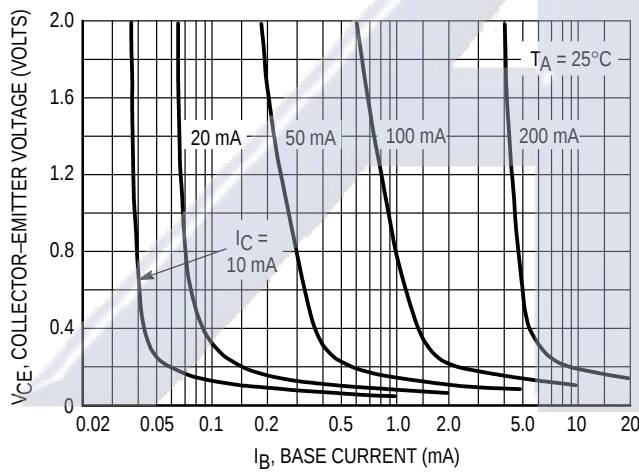


Figure 9. Collector Saturation Region

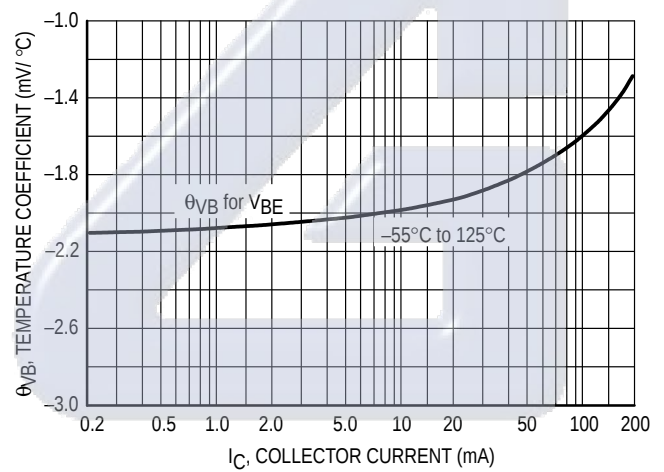


Figure 10. Base-Emitter Temperature Coefficient

BC546

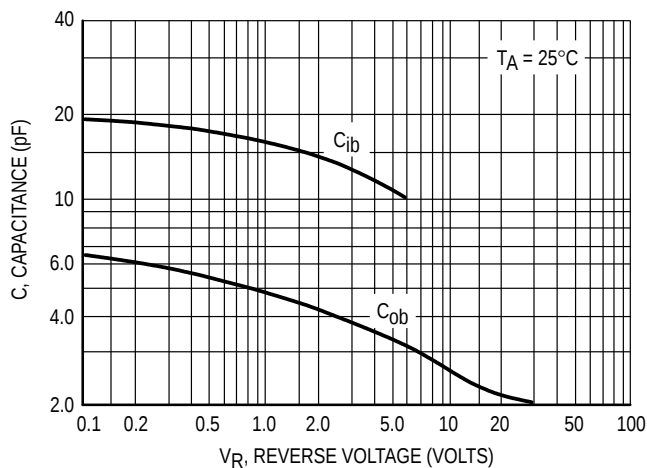


Figure 11. Capacitance

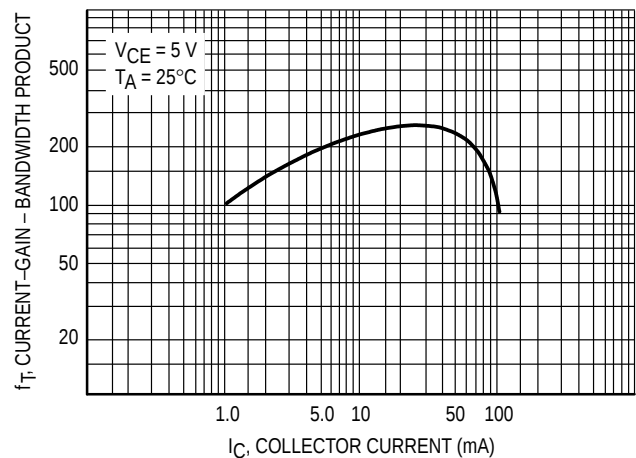
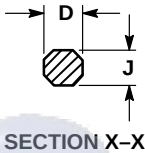
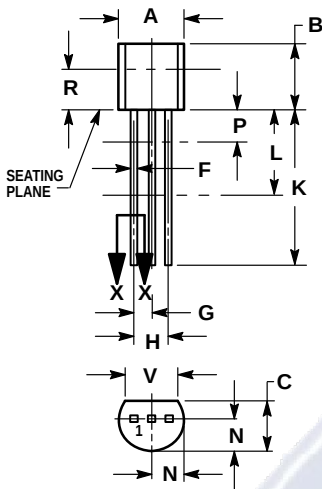


Figure 12. Current-Gain - Bandwidth Product

PACKAGE DIMENSIONS



- NOTES:
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 - 2. CONTROLLING DIMENSION: INCH.
 - 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 - 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K. MINIMUM LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

CASE 029-04
(TO-226AA)
ISSUE AD

- STYLE 17:
- PIN 1. COLLECTOR
 - 2. BASE
 - 3. EMITTER

Electrónica S.A. de C.V.